

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





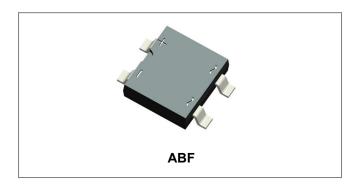








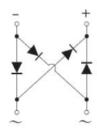
FTB1F-15F THRU FTB10F-15F 1.5A SURFACE MOUNT GLASS PASSIVATED BRIDGE RECTIFIER



Features

- Glass Passivated Chip Junction
- Reverse Voltage 100 to 1000 V
- Forward Current 1.5 A
- Designed for Surface Mount Application
- Fast reverse recovery time
- This is a Halogen Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

Case: ABF

Terminals: Solderable per MIL-STD-750, Method 2026

Weight: 82 mg

Maximum Ratings @TA=25°C unless otherwise specified

Single Phase half wave 60Hz, resistive or inductive load. For capacitive load current derate by 20%.

Characteristic	Symbol	FTB1F -15F	FTB2F -15F	FTB4F -15F	FTB6F -15F	FTB8F -15F	FTB10F -15F	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	100	200	400	600	800	1000	V
RMS Reverse Voltage	V _{RMS}	70	140	280	420	560	700	V
Average Forward Output Current @ T _A =50°C	I _{F(AV)}	1.5						Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	50						A

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Electrical Characteristics @TA=25°C unless otherwise specified

Characteristic	Symbol	FTB1F -15F	FTB2F -15F	FTB4F -15F	FTB6F -15F	FTB8F -15F	FTB10F -15F	Units
Forward voltage per element @ I _F =1.5A	V _F	1.3						
Maximum DC reverse current $T_A = 25^{\circ}C$ at rated DC blocking voltage $T_A = 125^{\circ}C$	I _R	5 100				μA		
Typical Junction Capacitance (Note 1)	CJ	25					pF	
Maximum Reverse Recovery Time (Note 3)	Im Reverse Recovery Time (Note 3) T_{rr} $T_{rr(TYP.)}$ 500 300					ns		

^{*} Pulse width < 300 µs, duty cycle < 2%

Thermal-Mechanical Specifications @TA=25°C unless otherwise specified

Characteristic	Symbol	FTB1F -15F	FTB2F -15F	FTB4F -15F	FTB6F -15F	FTB8F -15F	FTB10F -15F	Units
Typical Thermal Resistance (Note 2)	R _{θJA}	80					°C/W	
Operating and storage temperature range	T_J, T_{STG}	-55 to +150				°C		

- Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.
 - 2. Mounted on glass epoxy PC board with $4 \times (5 \times 5 \text{mm}^2)$ copper pad.
 - 3. Reverse Recovery Test Conditions: IF=0.5A, IR=1.0A, IRR=0.25A

Ratings and Characteristics Curves

Fig.1 Average Rectified Output Current Derating Curve

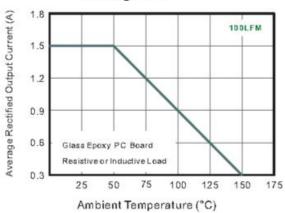
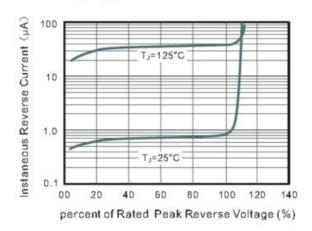


Fig.2 Typical Reverse Characteristics



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Fig.3 Typical Instaneous Forward Characteristics

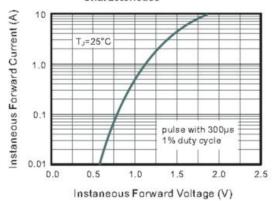


Fig.4 Typical Junction Capacitance

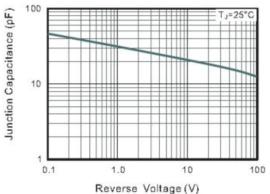
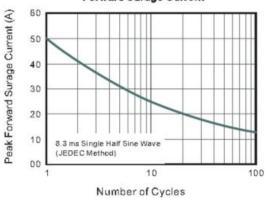
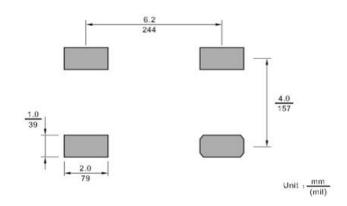


Fig.5 Maximum Non-Repetitive Peak Forward Surage Current





Ordering Information

Device	Package	Plating	Shipping
FTB1F-15F THRU FTB10F-15F	ABF	Pure Sn	5000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

Type number	Marking code			
FTB1F-15F	F15F1F			
FTB2F-15F	F15 F2F			
FTB4F-15F	F15F4F			
FTB6F-15F	F15F6F			
FTB8F-15F	F15F8F			
FTB10F-15F	F15F10F			
F15F	xxF			

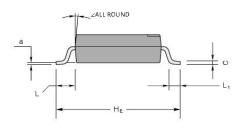
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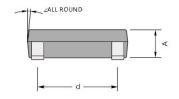


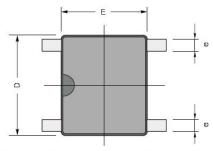




Mechanical Dimensions ABF(Inches/Millimeters)

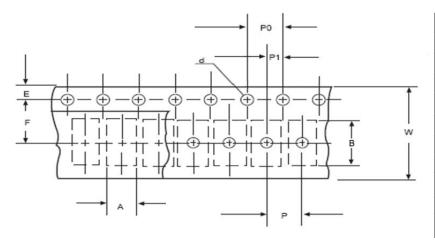






UNIT		Α	С	D	Е	H _E	d	е	L	L ₁	а	Z
mm	max	1.2	0.22	5.2	4.5	6.4	4.2	0.7	0.95	0.6	0.2	7°
111111	min	1.0	0.15	4.9	4.2	6.0	3.8	0.5				
!!	max	47	8.7	205	177	252	165	28	37	24	4	,
mil	min	39	5.9	193	166	236	150	20				

Carrier Tape Specification ABF



SYMBOL	Millimeters					
STRIBOL	Min.	Max.				
Α	5.00	5.40				
В	6.40	6.80				
d	1.40	1.60				
E	1.40	1.60				
F	5.55	5.75				
Р	3.90	4.10				
P0	3.90	4.10				
P1	1.90	2.10				
W	11.50	12.50				

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